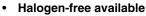




N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$ $I_{D}(A)$		Q _g (Typ.)		
30	$0.0042 \text{ at V}_{GS} = 10 \text{ V}$	23	30.5		
	0.0059 at $V_{GS} = 4.5 \text{ V}$	20	30.5		

FEATURES



TrenchFET[®] Power MOSFET

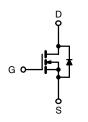
Optimized for "Low Side" Synchronous **Rectifier Operation**

New Low Thermal Resistance PowerPAK® Package with Low 1.07 mm Profile

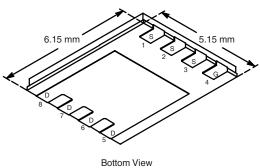
100 % R_q Tested

APPLICATIONS

- DC/DC Converters
- **Synchronous Rectifiers**



PowerPAK SO-8



Ordering Information: Si7358ADP-T1-E3 (Lead (Pb)-free)

Si7358ADP-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	30		V	
Gate-Source Voltage		V_{GS}	± 20			
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	I _D	23	14		
Continuous Diain Current (1) = 150 °C)	T _A = 70 °C		18	11		
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	60		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	4.5	1.6		
Avalanche Current	L = 0.1 mH	I _{AS}	50			
Maximum Dawar Dissipation	T _A = 25 °C	P _D 5.4 3.4	1.9	W		
Maximum Power Dissipation ^a	T _A = 70 °C		3.4	1.2	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) ^{b, c}			260			

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manifestore Locality to Application	t ≤ 10 s	R _{thJA}	18	23	°C/W	
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	50	65		
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	1.0	1.5		

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

Vishay Siliconix



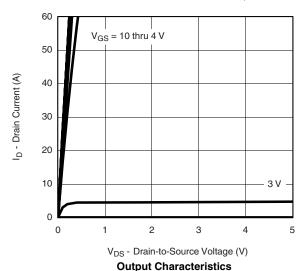
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	1.0		3.0	٧	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zana Oata Wallana Busin Ouwant	1	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α	
D : 0	D	$V_{GS} = 10 \text{ V}, I_D = 23 \text{ A}$		0.0032 0.0042		0	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		0.0045	0.0059	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 23 A		90		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 4.5 A, V _{GS} = 0 V		0.75	1.1	V	
Dynamic ^b							
Input Capacitance	C _{iss}			4650		pF	
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{SS} = 0 \text{ V}, f = 1 \text{ kHz}$		880			
Reverse Transfer Capacitance	C _{rss}			390			
Total Gate Charge	Q_g			30.5	40		
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 23 \text{ A}$		12.5		nC	
Gate-Drain Charge	Q_{gd}			10			
Gate Resistance	R_g		0.5	1.0	1.5	Ω	
Turn-On Delay Time	t _{d(on)}			21	35		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		10	20		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_G = 6 Ω		83	130	ns	
Fall Time	t _f			27	45		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, di/dt = 100 A/μs		50	80		

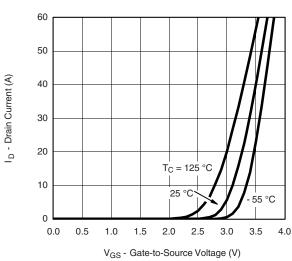
Notes:

- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





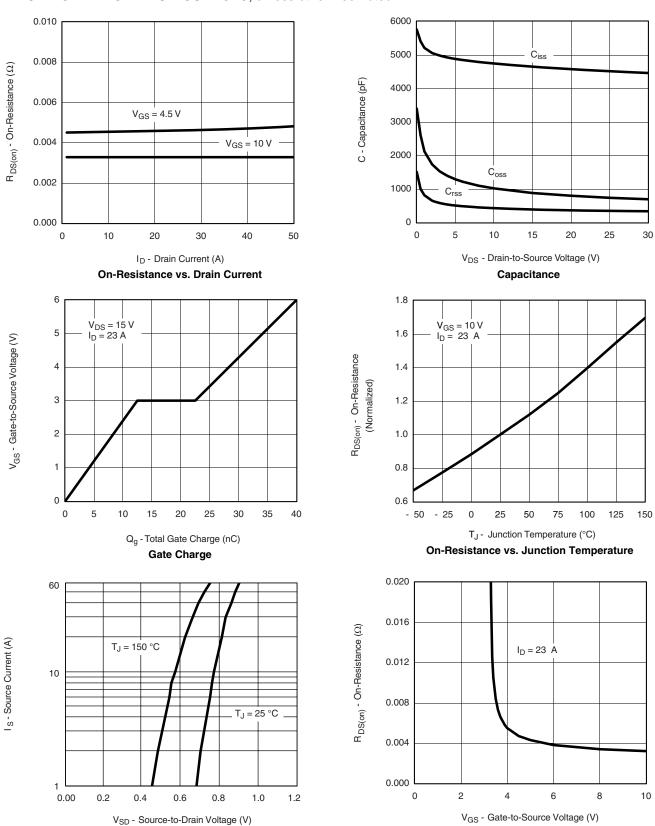
Transfer Characteristics







TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



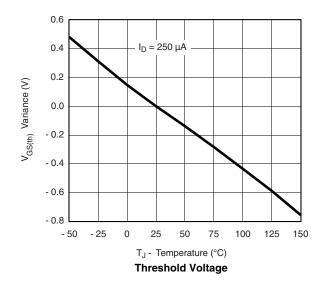
Source-Drain Diode Forward Voltage

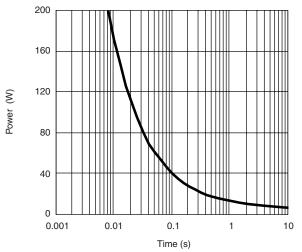
On-Resistance vs. Gate-to-Source Voltage

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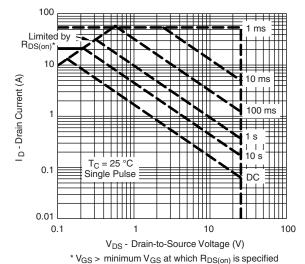
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

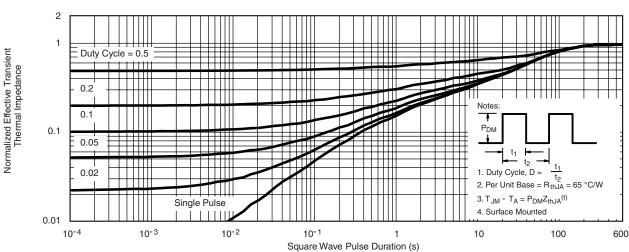




Single Pulse Power, Junction-to-Ambient



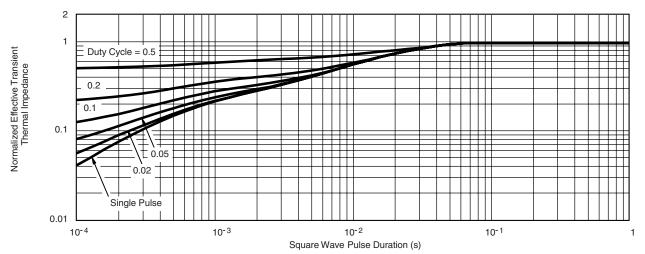
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?73161.

Document Number: 73161 www S-80438-Rev. E, 03-Mar-08



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